# MMBD2837LT1, MMBD2838LT1

# Monolithic Dual Switching Diodes

### Features

• Pb–Free Packages are Available



Rating	Symbol	Value	Unit
Peak Reverse Voltage	V <sub>RM</sub>	75	Vdc
D.C. Reverse Voltage MMBD2837LT1 MMBD2838LT1	V <sub>R</sub>	30 50	Vdc
Peak Forward Current	I <sub>FM</sub>	450 300	mAdc
Average Rectified Current	Ι <sub>Ο</sub>	150 100	mAdc

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

## THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$	PD	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$	PD	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

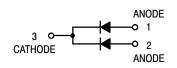
1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.



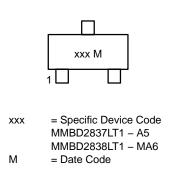
# **ON Semiconductor®**

http://onsemi.com





## MARKING DIAGRAM



#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBD2837LT1	SOT-23	3000 Tape & Reel
MMBD2837LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
MMBD2838LT1	SOT-23	3000 Tape & Reel
MMBD2838LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel

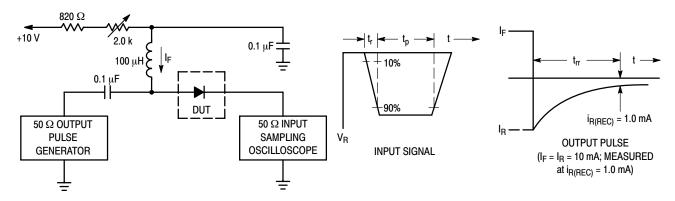
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MMBD2837LT1, MMBD2838LT1

## **ELECTRICAL CHARACTERISTICS (EACH DIODE)** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Reverse Breakdown Voltage ( $I_{(BR)}$ = 100 µAdc)	MMBD2837LT1 MMBD2838LT1	V <sub>(BR)</sub>	35 75	-	Vdc
Reverse Voltage Leakage Current (Note 3.) ( $V_R = 30 \text{ Vdc}$ ) ( $V_R = 50 \text{ Vdc}$ )	MMBD2837LT1 MMBD2838LT1	I <sub>R</sub>		0.1 0.1	μAdc
Diode Capacitance (V <sub>R</sub> = 0 V, f = 1.0 MHz)		CT	-	4.0	pF
Forward Voltage ( $I_F = 10 \text{ mAdc}$ ) ( $I_F = 50 \text{ mAdc}$ ) ( $I_F = 100 \text{ mAdc}$ )		V <sub>F</sub>	- - -	1.0 1.0 1.2	Vdc
Reverse Recovery Time ( $I_F = I_R = 10 \text{ mAdc}, I_{R(REC)} = 1.0 \text{ m}$	nAdc) (Figure 1)	t <sub>rr</sub>	-	4.0	ns

3. For each individual diode while the second diode is unbiased.

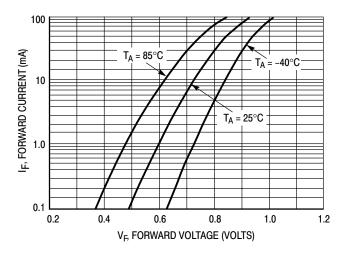


Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 10 mA. Notes: 2. Input pulse is adjusted so I<sub>R(peak)</sub> is equal to 10 mA. Notes: 3. t<sub>p</sub> » t<sub>rr</sub>

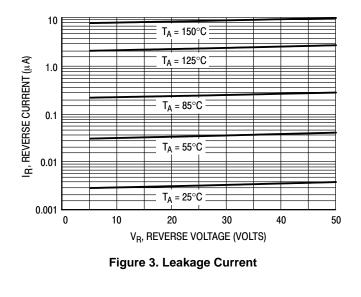
#### Figure 1. Recovery Time Equivalent Test Circuit

## MMBD2837LT1, MMBD2838LT1

## **CURVES APPLICABLE TO EACH CATHODE**







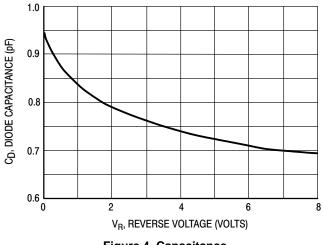
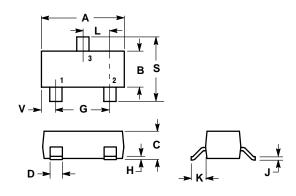


Figure 4. Capacitance

### MMBD2837LT1, MMBD2838LT1

#### PACKAGE DIMENSIONS

SOT-23 (TO236) CASE 318-18 **ISSUE AK** 



NOTES DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

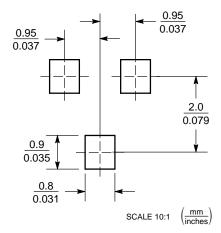
- CONTROLLING DIMENSION: INCH. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD 3. THICKNESS IS THE MINIMUM THICKNESS OF
- BASE MATERIAL. 318-01 THRU -07 AND -09 OBSOLETE, NEW 4 STANDARD 318-08.

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.1102	0.1197	2.80	3.04
В	0.0472	0.0551	1.20	1.40
С	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
н	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
к	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
v	0.0177	0.0236	0.45	0.60

STYLE 9:

PIN 1. ANODE ANODE 2. 3. CATHODE

#### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and in the registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights or the rights of others. SCILLC products are not designed, intended, or authorized for use a components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.